



Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirement of Automotive Applications.

Features

- BV_{CEO} > 75V
- $I_C = 3A$ High Continuous Current
- I_{CM} = 10A Peak Pulse Current
- High Gain Holds up $h_{FE} > 300 @ I_C=1A$
- Low Equivalent On-Resistance; $R_{CE(SAT)} = 78m\Omega$ at 4.5A
- Excellent h_{FE} Characteristics up to 10A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

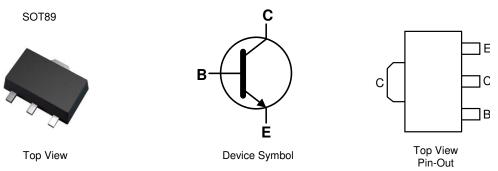
75V NPN MEDIUM POWER TRANSISTOR IN SOT89

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.05 grams (Approximate)

Applications

- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC DC Modules
- Backlight Inverters
- Power Switches
- MOSFET Gate Drivers



Ordering Information (Notes 4 and 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FCX1053AQTA	053	7	12	1,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

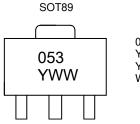
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Haloger- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



053 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 7 = 2017) WW = Week Code (01 to 53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	75	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	3	A
Base Current	I _B	500	mA
Peak Pulse Current	I _{CM}	10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	(Note 6)		1	
Power Dissipation	(Note 7)	PD	1.6	W
	(Note 8)		2.0	
	(Note 6)		125	
Thermal Resistance, Junction to Ambient Air	(Note 7)	R _{0JA}	78	°C/W
	(Note 8)		62.5	
Thermal Resistance, Junction to Lead	(Note 9)	R _{0JL}	3.6	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

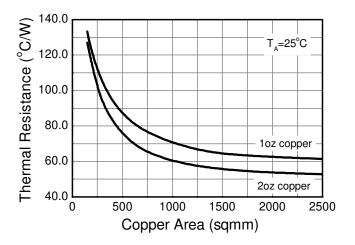
7. Same as note 6, except the device is mounted on 25mm x 25mm 1oz copper.

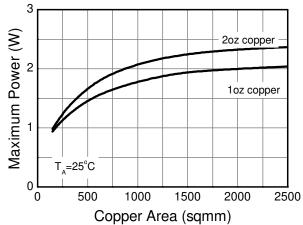
8. Same as note 6, except the device is mounted on 50mm x 50mm 1oz copper.

9. Thermal resistance from junction to solder-point (on the exposed collector pad).

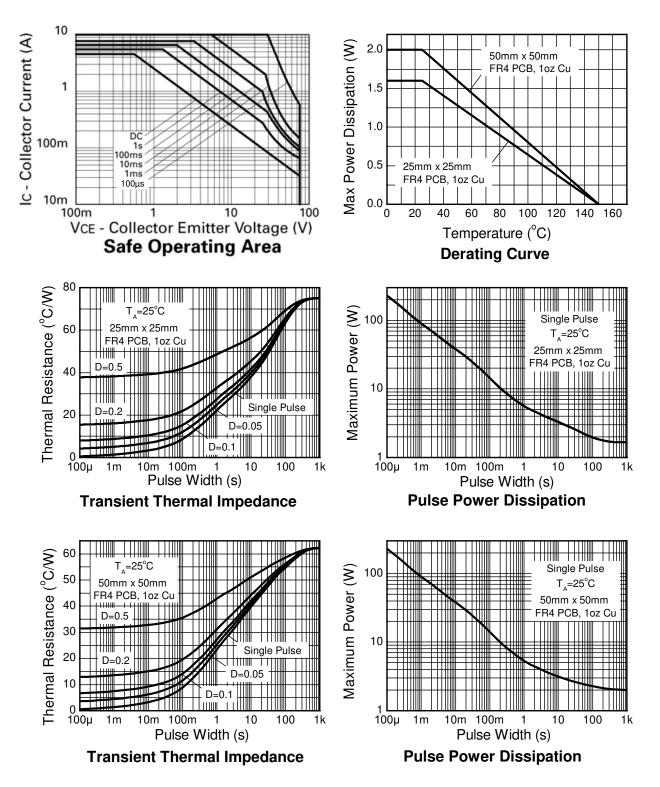
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information











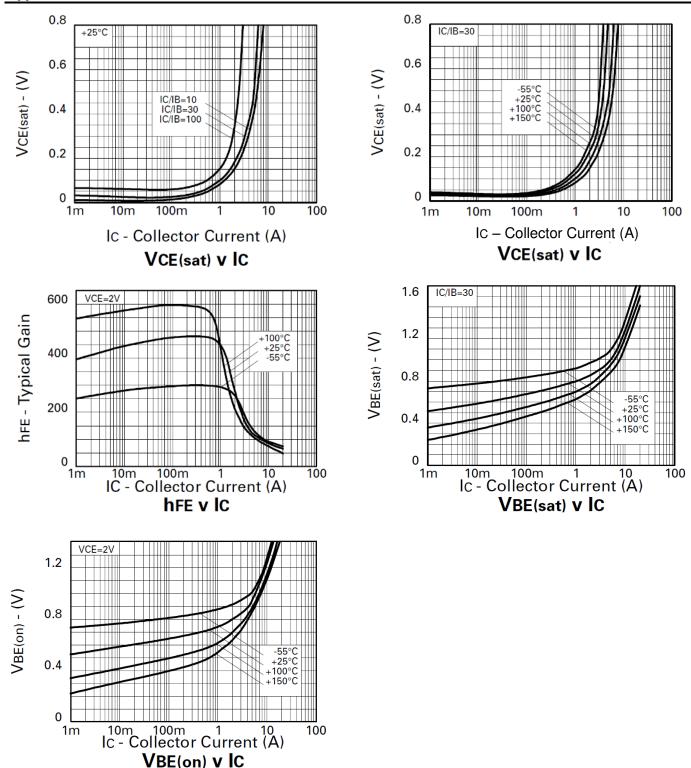
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	250	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CES}	150	250	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	75	100	_	V	$I_{\rm C} = 10 {\rm mA}$
Collector-Emitter Breakdown Voltage	BV _{CEV}	150	250	—	V	$I_{C} = 100 \mu A, V_{EB} = 1 V$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.8	—	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	—	0.9	50	nA	V _{CB} = 120V
Collector Cutoff Current	I _{CES}	—	1.5	50	nA	V _{CES} = 120V
Emitter Cutoff Current	I _{EBO}	—	0.3	20	nA	$V_{EB} = 5.6V$
DC Current Transfer Static Ratio (Note 11)	hfe	270 300 300 40 —	440 450 450 60 20	 1200 	_	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 0.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 4.5 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 10 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(SAT)}	_	21 55 150 160 350	30 75 200 210 440	mV	$\begin{split} I_{C} &= 0.2A, \ I_{B} = 20mA \\ I_{C} &= 0.5A, \ I_{B} = 20mA \\ I_{C} &= 1A, \ I_{B} = 10mA \\ I_{C} &= 2A, \ I_{B} = 100mA \\ I_{C} &= 4.5A, \ I_{B} = 200mA \end{split}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(SAT)}	—	900	1000	mV	$I_{C} = 3A, I_{B} = 100mA$
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(ON)}	—	825	950	mV	$I_C = 3A, V_{CE} = 2V$
Transitional Frequency	fT	_	140	_	MHz	$\label{eq:IC} \begin{array}{l} I_C = 50 \text{mA}, \ V_{CE} = 10 \text{V}, \\ f = 100 \text{MHz} \end{array}$
Output Capacitance	C _{obo}	_	21	30	pF	V _{CB} = 10V, f = 1MHz
Switching Time	ton		162		ns	$V_{CC} = 50V, I_C = 2A,$
Switching Time	t _{OFF}		900	_	ns	$I_{B1} = -I_{B2} = \pm 20 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.



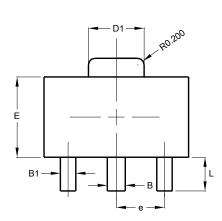
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

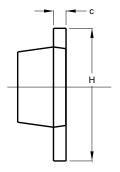




Package Outline Dimensions

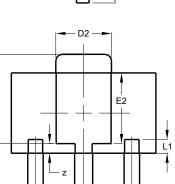
Please see http://www.diodes.com/package-outlines.html for the latest version.





SOT89

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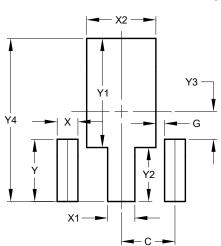


H1

SOT89							
Dim	Min	Max	Тур				
Α	1.40	1.60	1.50				
В	0.50	0.62	0.56				
B1	0.42	0.54	0.48				
С	0.35	0.43	0.38				
D	4.40	4.60	4.50				
D1	1.62	1.83	1.733				
D2	1.61	1.81	1.71				
Е	2.40	2.60	2.50				
E2	2.05	2.35	2.20				
е	-	-	1.50				
Н	3.95	4.25	4.10				
H1	2.63	2.93	2.78				
L	0.90	1.20	1.05				
L1	0.327	0.527	0.427				
z	0.20	0.40	0.30				
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value			
Dimensions	(in mm)			
С	1.500			
G	0.244			
Х	0.580			
X1	0.760			
X2	1.933			
Y	1.730			
Y1	3.030			
Y2	1.500			
Y3	0.770			
Y4	4.530			

SOT89



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